# 2SB1218G

### Silicon PNP epitaxial planar type

For general amplification Complementary to 2SD1819G

#### Features

- $\bullet$  High forward current transfer ratio  $h_{F\!E}$
- S-Mini type package, allowing downsizing of the equipment and automatic insertion through the tape packing and the magazine packing.

#### Absolute Maximum Ratings $T_a = 25^{\circ}C$

| a                                     |                  |             |      |  |  |  |  |
|---------------------------------------|------------------|-------------|------|--|--|--|--|
| Parameter                             | Symbol           | Rating      | Unit |  |  |  |  |
| Collector-base voltage (Emitter open) | V <sub>CBO</sub> | -45         | V    |  |  |  |  |
| Collector-emitter voltage (Base open) | V <sub>CEO</sub> | -45         | V    |  |  |  |  |
| Emitter-base voltage (Collector open) | V <sub>EBO</sub> | -7          | V    |  |  |  |  |
| Collector current                     | I <sub>C</sub>   | -100        | mA   |  |  |  |  |
| Peak collector current                | I <sub>CP</sub>  | -200        | mA   |  |  |  |  |
| Collector power dissipation           | P <sub>C</sub>   | 150         | mW   |  |  |  |  |
| Junction temperature                  | Tj               | 150         | °C   |  |  |  |  |
| Storage temperature                   | T <sub>stg</sub> | -55 to +150 | °C   |  |  |  |  |

#### Package

- Code
- SMini3-F2
- Marking Symbol: B
- Pin Name
  - 1. Base
  - 2. Emitter
  - 3. Collector

#### Electrical Characteristics $T_a = 25^{\circ}C \pm 3^{\circ}C$

| Parameter                                    | Symbol               | Conditions   | Min | Тур   | Max   | Unit |
|--|----------------------|--|-----|-------|-------|------|
| Collector-base voltage (Emitter open)        | V <sub>CBO</sub>     | $I_{C} = -10 \ \mu A, I_{E} = 0$                     | -45 |       |       | V    |
| Collector-emitter voltage (Base open)        | V <sub>CEO</sub>     | $I_{\rm C} = -2 \text{ mA}, I_{\rm B} = 0$           | -45 |       |       | V    |
| Emitter-base voltage (Collector open)        | V <sub>EBO</sub>     | $I_E = -10 \ \mu A, \ I_C = 0$                       | -7  |       |       | V    |
| Collector-base cutoff current (Emitter open) | I <sub>CBO</sub>     | $V_{CB} = -20 \text{ V}, I_E = 0$                    |     |       | - 0.1 | μΑ   |
| Collector-emitter cutoff current (Base open) | I <sub>CEO</sub>     | $V_{CE} = -10 \text{ V}, I_B = 0$                    |     |       | -100  | μΑ   |
| Forward current transfer ratio *             | h <sub>FE</sub>      | $V_{CE} = -10 \text{ V}, I_C = -2 \text{ mA}$        | 160 |       | 460   | _    |
| Collector-emitter saturation voltage         | V <sub>CE(sat)</sub> | $I_{C} = -100 \text{ mA}, I_{B} = -10 \text{ mA}$    |     | - 0.3 | - 0.5 | V    |
| Transition frequency                         | f <sub>T</sub>       | $V_{CB} = -10$ V, $I_E = 1$ mA, $f = 200$ MHz        |     | 80    |       | MHz  |
| Collector output capacitance                 | C <sub>ob</sub>      | $V_{CB} = -10 \text{ V}, I_E = 0, f = 1 \text{ MHz}$ |     | 2.7   |       | pF   |
| (Common base, input open circuited)          |                      |  |     |       |       |      |

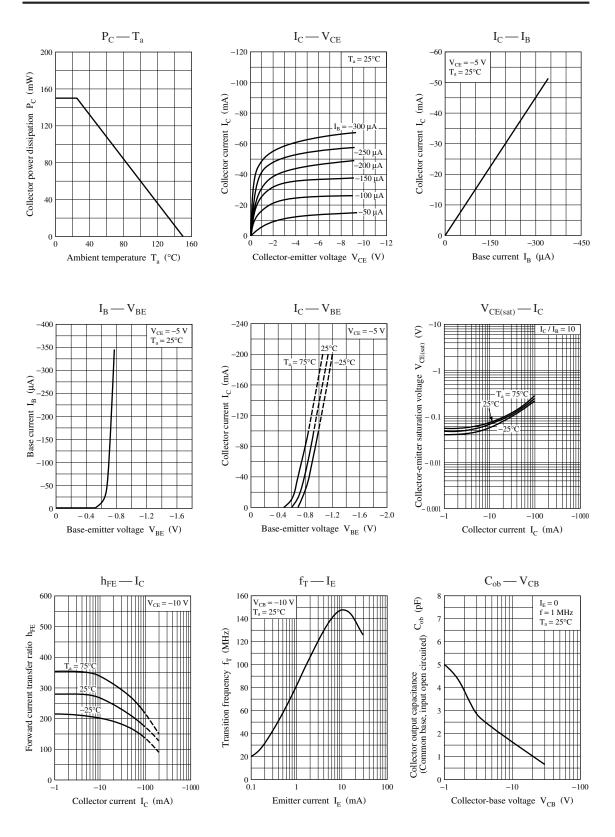
Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 measuring methods for transistors.

2. \*: Rank classification

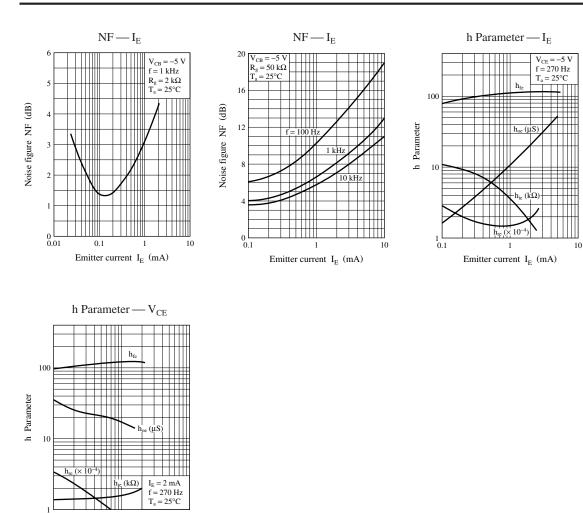
| Rank           | Q          | R          | S          | No-rank    |
|----------------|------------|------------|------------|------------|
| $h_{\rm FE}$   | 160 to 260 | 210 to 340 | 290 to 460 | 160 to 460 |
| Marking symbol | BQ         | BR         | BS         | В          |

Product of no-rank is not classified and have no marking symbol for rank.

### Panasonic



# **Panasonic** This product complies with the RoHS Directive (EU 2002/95/EC).



1 -10 -1Collector-emitter voltage V<sub>CE</sub> (V)

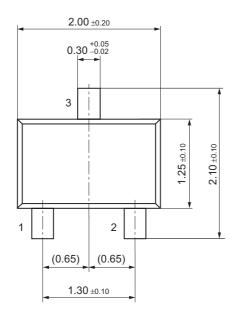
-1

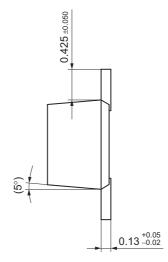
-100

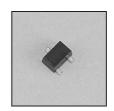
### **Panasonic**

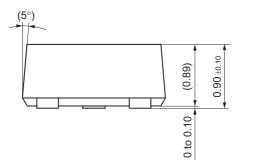
### SMini3-F2

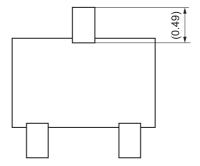
Unit: mm











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